

### LC723481W,723482W,723483W

#### Low-Voltage ETR-Controller

#### Overview

The LC723481W, 723482W, and 723483W are low-voltage electronic tuning radio microcontrollers that include a PLL that operates up to 250 MHz and a 1/4 duty 1/2 bias LCD driver on chip. These ICs include an on-chip DC-DC converter, making it is easy to create the supply voltages required for tuning and allowing cost reductions in end products.

These ICs are optimal for use in low-voltage portable audio equipment that includes a radio receiver.

#### **Function**

• Program memory (ROM):

2048 × 16 bits (4K bytes)
 3072 × 16 bits (6K bytes)
 4096 × 16 bits (8K bytes)
 LC723482W
 LC723483W

• Data memory (RAM):

128 × 4 bits
 192 × 4 bits
 256 × 4 bits
 LC723481W
 LC723482W
 LC723483W

• Cycle time: 40 μs (all 1-word instructions) at 75kHz crystal oscillation

• Stack: 4 levels (8 levels)

LC723481W(LC723482W/3W)

- LCD driver: 48 to 80 segments (1/4 duty, 1/2 bias drive)
- Interrupts: One external interrupt

Timer interrupts (1, 5, 10, and 50 ms)

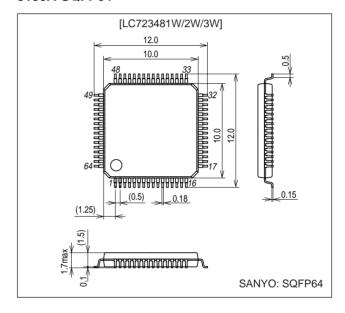
- A/D converter: Three input channels (5-bit successive approximation conversion)
- Input ports: 7 ports (of which 3 can be switched for use as A/D converter inputs)
- Output ports: 6 ports (of which 1 can be switched for use as the beep tone output and 2 are opendrain ports)

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#### **Package Dimensions**

unit: mm

#### 3190A-SQFP64



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I/O ports: 16 pins (Of these 8 can be switched over to function as LCD ports as a mask options.)

• PLL: Dead band control is supported. (Four types)
Reference frequencies: 1, 3, 3.125, 5, 6.25, 12.5,
and 25 kHz

Input frequencies: FM band: 10 to 250 MHz
 AM band: 0.5 to 40 MHz

· Input sensitivity:

FM band: 35 mVrms (50 mVrms at 130 MHz or higher frequency)

AM band: 35 mVrms

• IF counting: Using the HCTR input pin for 0.4 to 12 MHz signals

 External reset input: During CPU and PLL operations, instruction execution is started from location 0.

Built-in power-on reset circuit:
 The CPU starts execution from location 0 when power is first applied.

• Halt mode: The controller-operating clock is stopped.

• Backup mode: The crystal oscillator is stopped.

• Static power-on function: Backup state is cleared with the PF port

• Beep tone: 1.5625 and 3.125 kHz

• Built-in low-pass filter amplifier: This circuit obviates the need for an external amplifier for the PLL circuit and contributes to reduced end product costs.

• Built-in DC/DC converter:

Cost reduced in tuner-use power supply circuit

• Memory retention voltage: 0.9 V at least

V<sub>DD</sub> voltage

PLL: 1.8 to 3.6 VCPU: 1.4 to 3.6 VADC: 1.6 to 3.6 V

• Optional function switches:

— PH0 to PH3/S13 to S16

— PG0 to PG3/S17 to S20

PG0 to PG3 (open-drain output/general-purpose output)

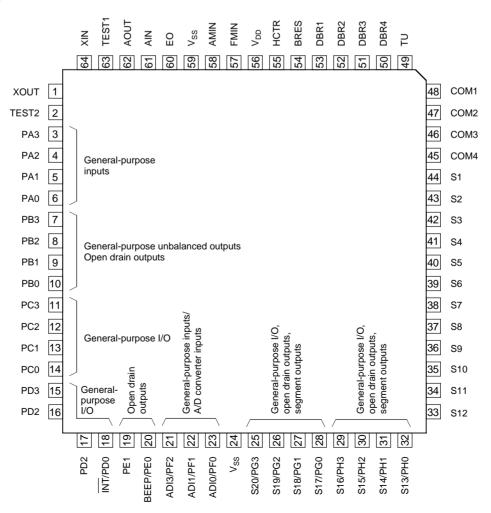
PH0 to PH3 (open-drain output/general-purpose output)

 FM DC/DC clock (75 kHz or 1/256 times the local FM oscillator frequency)

— AM DC/DC clock (1/2, 1/4, 1/8, or 1/16 times the AM local oscillator frequency)

• Package: SQFP-64 (0.5-mm pitch)

#### **Pin Assignment**



# Specifications Absolute Maximum Ratings at Ta = 25°C, $V_{SS}$ = 0 V

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>DD</sub> max		-0.3 to +4.0	V
Input voltage	V <sub>IN</sub>	All input pins	-0.3 to V <sub>DD</sub> +0.3	V
Output voltage	V <sub>OUT</sub> (1)	AOUT, PE, TU	-0.3 to +15	V
Output voltage	V <sub>OUT</sub> (2)	All output pins except V <sub>OUT</sub> (1)	-0.3 to V <sub>DD</sub> + 0.3	V
	I <sub>OUT</sub> (1)	PC, PD, PG, PH, EO	0 to 3	mA
	I <sub>OUT</sub> (2)	РВ	0 to 1	mA
Output current	I <sub>OUT</sub> (3)	AOUT, PE, TU	0 to 2	mA
	I <sub>OUT</sub> (4)	S1 to S20	300	μA
	I <sub>OUT</sub> (5)	COM1 to COM4	3	mA
Allowable power dissipation	Pdmax	$Ta = -20 \text{ to } +70^{\circ}\text{C}$	300	mW
Operating temperature	Topr		-20 to +70	°C
Storage temperature	Tstg		-45 to +125	°C

#### Allowable Operating Ranges at $Ta = -20~to~+70^{\circ}C,~V_{DD} = 1.8~to~3.6~V$

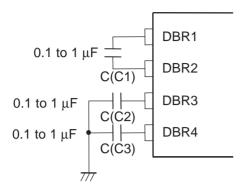
Parameter	Cumb al	Conditions		Ratings		Unit
Parameter	Symbol	Conditions	min	typ	max	Onit
	V <sub>DD</sub> (1)	PLL operating voltage	1.8	3.0	3.6	
Cumply voltage	V <sub>DD</sub> (2)	Memory retention voltage	1.0			V
Supply voltage	V <sub>DD</sub> (3)	CPU operating voltage	1.4	3.0	3.6	]
	V <sub>DD</sub> (4)	A/D converter operating voltage	1.6	3.0	3.6	
James de la constanta de la co	V <sub>IH</sub> (1)	Input ports other than V <sub>IH</sub> (2), V <sub>IH</sub> (3), AMIN, FMIN, HCTR, and XIN	0.7 V <sub>DD</sub>		V <sub>DD</sub>	V
Input high-level voltage	V <sub>IH</sub> (2)	BRES port	0.8 V <sub>DD</sub>		V <sub>DD</sub>	V
	V <sub>IH</sub> (3)	Port PF	0.6 V <sub>DD</sub>		V <sub>DD</sub>	V
la a colo la colo colo a colo	V <sub>IL</sub> (1)	Input ports other than V <sub>IL</sub> (2), V <sub>IL</sub> (3), AMIN, FMIN, HCTR, and XIN	0		0.3 V <sub>DD</sub>	V
Input low-level voltage	V <sub>IL</sub> (2)	BRES port	0		0.2 V <sub>DD</sub>	V
	V <sub>IL</sub> (3)	Port PF	0		0.2 V <sub>DD</sub>	V
	V <sub>IN</sub> (1)	XIN	0.5		0.6	Vrms
Input amplitude	V <sub>IN</sub> (2)	FMIN, AMIN	0.035		0.35	Vrms
Input amplitude	V <sub>IN</sub> (3)	FMIN	0.05		0.35	Vrms
	V <sub>IN</sub> (4)	HCTR	0.035		0.35	Vrms
Input voltage range	V <sub>IN</sub> (5)	ADIO, ADI1, ADI3	0		$V_{DD}$	V
	F <sub>IN</sub> (1)	XIN: CI ≤ 35 kΩ	70	75	80	kHz
	F <sub>IN</sub> (2)	FMIN: V <sub>IN</sub> (2), V <sub>DD</sub> (1)	10		130	MHz
Input fraguency	F <sub>IN</sub> (3)	FMIN: V <sub>IN</sub> (3), V <sub>DD</sub> (1)	130		250	MHz
Input frequency	F <sub>IN</sub> (4)	AMIN(H): V <sub>IN</sub> (2), V <sub>DD</sub> (1)	2		40	MHz
	F <sub>IN</sub> (5)	AMIN(L): V <sub>IN</sub> (2), V <sub>DD</sub> (1)	0.5		10	MHz
	F <sub>IN</sub> (6)	HCTR: V <sub>IN</sub> (4), V <sub>DD</sub> (1)	0.4		12	MHz

#### **Electrical Characteristics** within the allowable operating ranges

Parameter	Symbol	Conditions		Ratings		Unit
Falametei	Symbol	Conditions	min	typ	max	Offic
	I <sub>IH</sub> (1)	$XIN: V_I = V_{DD} = 3.0 \text{ V}$			3	μA
	I <sub>IH</sub> (2)	FMIN, AMIN, HCTR: V <sub>I</sub> = V <sub>DD</sub> = 3.0 V	3	8	20	μA
Input high-level current	I <sub>IH</sub> (3)	PA/PF (without pull-down resistors), the PC, PD, PG, PH, ports, and BRES: V <sub>I</sub> = V <sub>DD</sub> = 3.0 V			3	μA
	I <sub>IL</sub> (1)	XIN: V <sub>DD</sub> = V <sub>SS</sub>			-3	μΑ
	I <sub>IL</sub> (2)	FMIN, AMIN, HCTR: V <sub>I</sub> = V <sub>DD</sub> = V <sub>SS</sub>	-3	-8	-20	μA
Input low-level current	I <sub>IL</sub> (3)	PA/PF (without pull-down resistors), the PC, PD, PG, PH, ports, and BRES: V <sub>I</sub> = V <sub>DD</sub> = V <sub>SS</sub>			-3	μA
Input floating voltage	V <sub>IF</sub>	PA/PF (with pull-down resistors)			0.05 V <sub>DD</sub>	V
Dull deur vocieter volue	R <sub>PD</sub> (1)	PA/PF (with pull-down resistors), V <sub>DD</sub> = 3.0 V	75	100	200	kΩ
Pull-down resistor values	R <sub>PD</sub> (2)	TEST1, TEST2		10		kΩ
Hysteresis	V <sub>H</sub>	BRES	0.1 V <sub>DD</sub>	0.2 V <sub>DD</sub>		V
Voltage doubler reference voltage	DBR4	Referenced to $V_{DD}$ , $C(3) = 0.47 \mu F$ , $Ta = 25^{\circ}C^{*1}$	1.3	1.5	1.7	V
Voltage doubler step-up voltage	DBR1, 2, 3	$C(1) = 0.47 \mu\text{F}$ $C(2) = 0.47 \mu\text{F}$ , without loading, $Ta = 25^{\circ}\text{C}$ *1	2.7	3.0	3.3	V
	V <sub>OH</sub> (1)	PB: I <sub>O</sub> = -1 mA	V <sub>DD</sub> – 0.7 V <sub>DD</sub>		V <sub>DD</sub> – 0.3 V <sub>DD</sub>	V
	V <sub>OH</sub> (2)	PC, PD, PG, PH, : I <sub>O</sub> = −1 mA	V <sub>DD</sub> – 0.3 V <sub>DD</sub>			V
Output high-level voltage	V <sub>OH</sub> (3)	EO: I <sub>O</sub> = -500 μA	V <sub>DD</sub> – 0.3 V <sub>DD</sub>			V
	V <sub>OH</sub> (4)	XOUT: I <sub>O</sub> = 200 μA	V <sub>DD</sub> – 0.3 V <sub>DD</sub>			V
	V <sub>OH</sub> (5)	S1 to S20: I <sub>O</sub> = -20 μA *1	2.0			V
	V <sub>OH</sub> (6)	COM1, COM2, COM3, COM4: I <sub>O</sub> = -100 μA *1	2.0			V
	V <sub>OL</sub> (1)	PB: I <sub>O</sub> = -50 μA	0.3 V <sub>DD</sub>		0.7 V <sub>DD</sub>	V
	V <sub>OL</sub> (2)	PC, PD, PG, PH, PE: I <sub>O</sub> = -1 mA			0.3 V <sub>DD</sub>	V
	V <sub>OL</sub> (3)	EO: I <sub>O</sub> = -500 μA			0.3 V <sub>DD</sub>	V
	V <sub>OL</sub> (4)	XOUT: I <sub>O</sub> = -200 μA			0.3 V <sub>DD</sub>	V
Output low-level voltage	V <sub>OL</sub> (5)	S1 to S20: I <sub>O</sub> = -20 μA *1			1.0	V
	V <sub>OL</sub> (6)	COM1, COM2, COM3, COM4: I <sub>O</sub> = -100 µA *1			1.0	V
	V <sub>OL</sub> (7)	PE: I <sub>O</sub> = 2 mA			1.0	V
	V <sub>OL</sub> (8)	AOUT (AIN = 1.3 V), TU: I <sub>O</sub> = 1 mA, V <sub>DD</sub> = 3 V			0.5	V
Output off leakage current	I <sub>OFF</sub> (1)	Ports PB, PC, PD, PG, PH and EO	-3		+3	μA
Output Oil leakage Cufferit	I <sub>OFF</sub> (2)	AOUT, PE and port TU	-100		+100	nA
A/D converter error		ADI0, ADI1, ADI3, V <sub>DD</sub> (4)	-1/2		+1/2	LSB
	I <sub>DD</sub> (1)	V <sub>DD</sub> (1): F <sub>IN</sub> (2) 130 MHz, Ta = 25°C		5		mA
	I <sub>DD</sub> (2)	V <sub>DD</sub> (2): In HALT mode, Ta = 25°C *2		0.1		mA
Current drain	I <sub>DD</sub> (3)	$V_{DD}$ = 3.6 V, with the oscillator stopped, Ta = 25°C *3		1		μA
	I <sub>DD</sub> (4)	$V_{DD}$ = 1.8 V, with the oscillator stopped, Ta = 25°C *3		0.5		μA

Note: The halt mode current is due to the CPU executing 20 instruction steps every 125 ms.

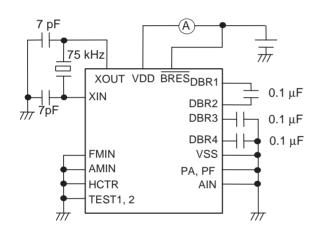
Note: \* C(1), C(2), and C(3) must be connected even if an LCD is not used.

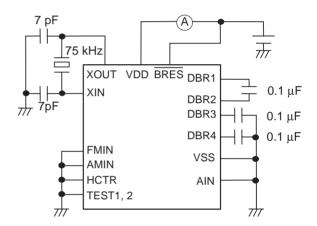


Notes: \*1. The capacitors C(1), C(2), and C(3) must be connected to the DBR pins.

\*2. Halt mode current measurement circuit

\*3. Backup mode current measurement circuit

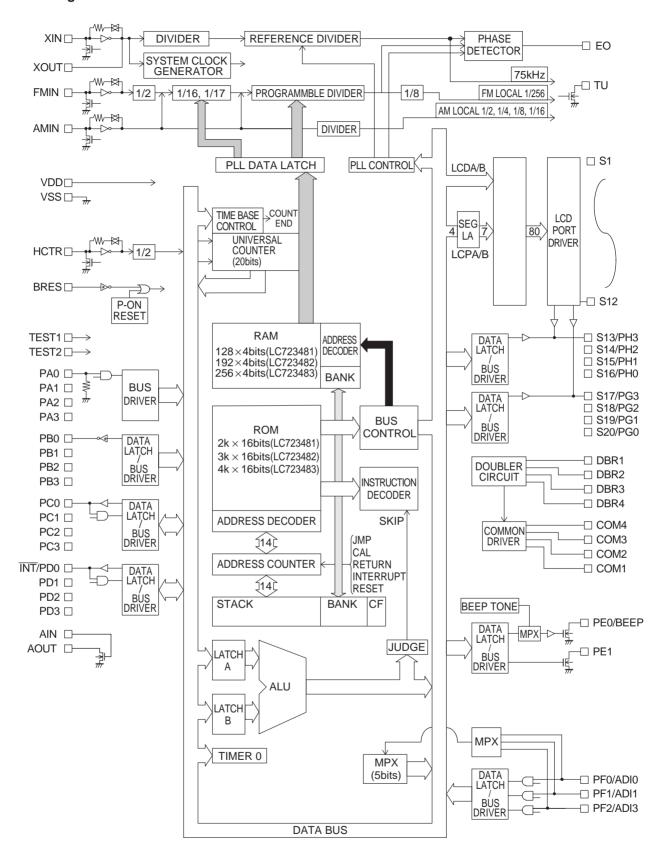




With all ports other than those specified above left open. With output mode selected for PC and PD. With segments S13 to S20 selected.

With all ports other than those specified above left open. With output mode selected for PC and PD. With segments S13 to S20 selected.

#### **Block Diagram**



#### **Pin Functions**

Pin No.	Pin	I/O	Function	I/O circuit
64 1	XIN XOUT	I 0	75 kHz oscillator connections	
63 2	TEST1 TEST2	I I	IC testing. These pins must be connected to ground during normal operation.	_
6 5 4 3	PA0 PA1 PA2 PA3	ı	Special-purpose key return signal input ports designed with a low threshold voltage. When used in conjunction with port PB to form a key matrix, up to 3 simultaneous key presses can be detected. The four pull-down resistors are selected together in a single operation using the IOS instruction (PWn = 2, b1); they cannot be specified individually. Input is disabled in backup mode, and the pull-down resistors are disabled after a reset.	Input with built-in pull-down resistor
10 9 8 7	PB0 PB1 PB2 PB3	0	General-purpose CMOS and n-channel open-drain output shared-function ports.  The IOS instruction (Pwn = 2) is used for function switching.  (b0: PB0, b2: PB1, b3: PB2, PB3) (0: general-purpose CMOS, 1: n-channel open-drain)  Special-purpose key source signal output ports. Since unbalanced CMOS output transistor circuits are used, diodes to prevent short-circuits when multiple keys are pressed are not required. These ports go to the output high-impedance state in backup mode. These ports go to the output high-impedance state after a reset and remain in that state until an output instruction (OUT, SPB, or RPB) is executed.  *: Verify the output impedance conditions carefully if these pins are used for functions other than key source outputs.	Unbalanced CMOS push-pull
14 13 12 11 18 17 16 15	PC0 PC1 PC2 PC3 INT0/PD0 PD1 PD2 PD3 *2	I/O	General-purpose I/O ports.  PD0 can be used as an external interrupt port. Input or output mode can be set individually using the IOS instruction (Pwn = 4, 5) by the bit . A value of 0 specifies input, and 1 specifies output. These ports go to the input disabled high-impedance state in backup mode. They are set to function as general-purpose input ports after a reset.	CMOS push-pull
20 19	BEEP/PE0 PE1	0	General-purpose output and BEEP output (PE0 shared function ports).  The BEEP instruction is used to switch the BEEP/PE0 port between the general-purpose output port and the BEEP output functions.  A BEEP instruction with b2 = 0 will set the BEEP/PE0 port to function as a general-purpose output port. If b2 is set to 1, the instruction will select the BEEP output function. Bits b0 and b1 switch the frequency of the BEEP output. This IC supports two BEEP frequencies.  *: When the PE0 port is set to function as the BEEP output, executing an output instruction for PE0 will only change the value of the internal output latch; it will have no effect on the output. Only the PE0 pin can be switched between the general-purpose output port and BEEP output functions; the PE1 pin is a dedicated general-purpose output port. In backup mode, these ports go to the high-impedance state. These ports will remain in that state until either an output instruction or a BEEP instruction is executed. Since these ports are open drain ports, a resistor must be inserted between each port and VDD. At reset, they are set to the general-purpose output port function.	N-channel open-drain

Continued from preceding page.

Pin No.	Pin	I/O	Function	I/O circuit
23 22 21	PF0/ADI0 PF1/ADI1 PF2/ADI3	ı	General-purpose input and A/D converter input shared function ports. The IOS instruction (Pwn = FH) is used to switch between the general-purpose input and A/D converter port functions. The general-purpose input and A/D converter port functions can be switched by the bit, with 0 specifying general-purpose input, and 1 specifying the A/D converter input function. To select the A/D converter function, set up the A/D converter pin with an IOS instruction with Pwn set to 1. The A/D converter is started with the UCC instruction (b3 = 1, b2 = 1). The ADCE flag is set when the conversion completes. The INR instruction is used to read in the data.  *: If an input instruction is executed for one of these pins which is set up for analog input, the read in data will be at the low level since CMOS input is disabled. In backup mode these pins go to the input disabled high-impedance state. These ports are set to their general-purpose input port function after a reset. The A/D converter is a 5-bit successive approximation type converter, and features a conversion time of 1.28 ms. Note that the full-scale A/D converter voltage (1FH) is (62/96) V <sub>DD</sub> .	CMOS input/analog input
25 26 27 28 29 30 31 32	PG3/S20 PG2/S19 PG1/S18 PG0/S17 PH3/S16 PH2/S15 PH1/S14 PH0/S13	0	Shared function ports that function either as LCD driver segment outputs or general-purpose I/O ports.  The IOS instruction is used to switch between the segment output and the general-purpose I/O port functions.  • When used as segment output ports  The IOS (Pwn=8) instruction is used to set the general-purpose I/O port.  b0 to 3 = S17 to S20/PG0 to PG3  (0: Segment output, 1: PG0 to PG3)  The IOS (Pwn=9) instruction is used to set the general-purpose I/O port.  b0 to 3 = S13 to S16/PH0 to PH3  (0: Segment output, 1: PH0 to PH3)  • When used as general-purpose I/O ports  The IOS instruction (Pwn=6, 7) is used to switch the I/O direction. The directions of these pins can be set individually in 1-bit units.	CMOS push-pull
33 to 44	S12 to S1	0	LCD driver segment output pins. A 1/4-duty 1/2-bias drive technique is used. The frame frequency is 75 Hz. In backup mode, the outputs are fixed at the low level. After a reset, the outputs are fixed at the low level.	CMOS push-pull
45 46 47 48	COM4 COM3 COM2 COM1	0	LCD driver common output pins. A 1/4-duty 1/2-bias drive technique is used. The frame frequency is 75 Hz. In backup mode, the outputs are fixed at the low level. After a reset, the outputs are fixed at the low level.	
50 51 52 53	DBR4 DBR3 DBR2 DBR1	I	LCD power supply step-up voltage inputs.	

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Pin No.	Pin	I/O			Fund	tion				I/O circuit
54	BRES	ı		mode or cycle to r	eset the syste	m ar	nd restart exec	utio	low level for at least n with the PC set to r on reset circuit.	
49	TU	0	Tuning voltage ge These pins inclu connecting extern	ide a n-cl	n transistor, a			ес	an be generated by	N-channel open-drain
55	HCTR	ı	measurement a UCC instruct  UCS b3 b2  0 0  0 1  1 0  The CNTEND fla as an AC amplifice	frequency freque	Measureme mode  Frequency measureme  — then the count node, the input	nt nt comp	UCS b1 b	00 00 11 00 11	ment mode and the distart the count with  Measurement time  1 ms 4 ms 8 ms 32 ms  Aput circuit functions pupled.  Indeed, PLL stop mode,	CMOS amplifier input
57	FMIN	I	FM VCO (local os This pin is selecte The input must b Input is disabled	CW1	b1, b0 0 0 or coupled.	10	Bandwidth ) to 250 MHz	and	in PLL stop mode.	CMOS amplifier input
58	AMIN	I	AM VCO (local of This pin and the but	candwidth  CW1	b1, b0 1 0 1 1 0. r coupled.	2 to 5 to ′	Bandwidth 40 MHz (SW) 0 MHz (MW, L	_W)	CW1.	CMOS amplifier input

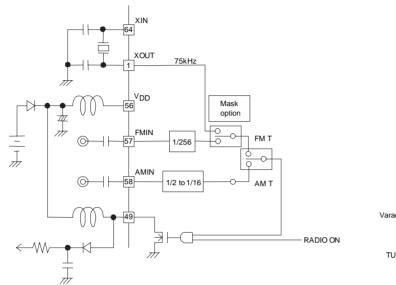
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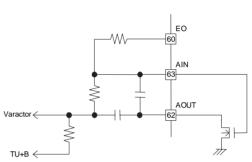
Pin No.	Pin	I/O	Function	I/O circuit
60	EO	0	Main charge pump output. When the local oscillator frequency divided by N is higher than the reference frequency a high level is output, when lower, a low level is output. The pin is set to the high-impedance state when the frequencies match. Output goes to the high-impedance state in backup mode, in halt mode, after a reset, and in PLL stop mode.	CMOS push-pull
61 62	AIN AOUT	0	Connections for the built-in transistor used to form a low-pass filter.	
24 59 56	V <sub>SS</sub> V <sub>SS</sub> V <sub>DD</sub>	_	Power supply pin. This pin must be connected to ground.  This pin must be connected to ground.  This pin must be connected to V <sub>DD</sub> .	_

Note 2: When a pin in an I/O switching port is used as an output, applications must first set up the data with an OUT, SPB, or RPB instruction and then set up output mode with an IOS instruction.

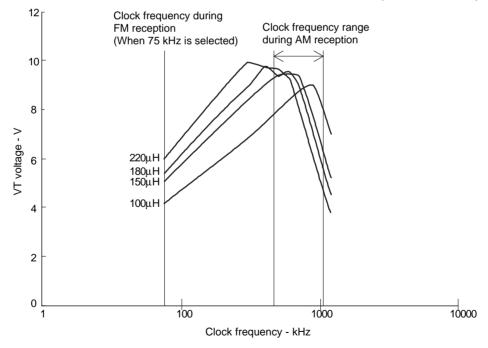
## Sample Application for Tuning Voltage Generation Circuit

#### Sample Application for Low-Pass Filter Amplifier





#### LC723481 DC-DC converter load = 100 kW (When VDD = 1.8 V)



#### LC723481W, 723482W and 723483W Series Instruction Set

#### **Terminology**

ADDR : Program memory address

b : Borrow C : Carry

DH : Data memory address High (Row address) [2 bits]
DL : Data memory address Low (Column address) [4 bits]

I : Immediate data [4 bits]
M : Data memory address
N : Bit position [4 bits]
Rn : Resister number [4 bits]
Pn : Port number [4 bits]

PW : Port control word number [4 bits]

r : General register (One of the addresses from 00H to 0FH of BANK0)

( ), [ ] : Contents of register or memory M (DH, DL) : Data memory specified by DH, DL

Instruc-	Managaria	Ope	rand	- Franchisco	0						Ir	nstructio	on forma	t				$\neg$
tions	Mnemonic	1st	2nd	Function	Operations function	f	е	d	С	b	a 9 8 7 6 5 4 3		2	1	0			
	AD	r	М	Add M to r	$r \leftarrow (r) + (M)$	0	1	0	0	0	0	DH	DI	_		r		٦
	ADS	r	М	Add M to r, then skip if carry	$r \leftarrow (r) + (M)$ , skip if carry	0	1	0	0	0	1	DH	DI	_		r		
Suc	AC	r	М	Add M to r with carry	$r \leftarrow (r) + (M) + C$	0	1	0	0	1	0	DH	DI	-		r		٦
Addition instructions	ACS	r	М	Add M to r with carry, then skip if carry	$r \leftarrow (r) + (M) + C$ skip if carry	0	1	0	0	1	1	DH	DI	-		r		
n in	AI	М	ı	Add I to M	$M \leftarrow (M) + I$	0	1	0	1	0	0	DH	DI	-		I		П
ditic	AIS	М	ı	Add I to M, then skip if carry	$M \leftarrow (M) + I$ , skip if carry	0	1	0	1	0	1	DH	DI	-		I		П
Ad	AIC	М	ı	Add I to M with carry	$M \leftarrow (M) + I + C$	0	1	0	1	1	0	DH	DI	-		I		П
	AICS	М	ı	Add I to M with carry, then skip if carry	$M \leftarrow (M) + I + C$ , skip if carry	0	1	0	1	1	1	DH	DI	-		ı		
	SU	r	М	Subtract M from r	$r \leftarrow (r) - (M)$	0	1	1	0	0	0	DH	DI	-		r		П
S	SUS	r	М	Subtract M from r, then skip if borrow	$r \leftarrow (r) - (M),$ skip if borrow	0	1	1	0	0	1	DH	DI	-		r		
tion	SB	r	М	Subtract M from r with borrow	$r \leftarrow (r) - (M) - b$	0	1	1	0	1	0	DH	DI	_		r		
Subtraction instructions	SBS	r	М	Subtract M from r with borrow, then skip if borrow	$r \leftarrow (r) - (M) - b$ , skip if borrow	0	1	1	0	1	1	DH	DI	-		r		
tion	SI	М	ı	Subtract I from M	$M \leftarrow (M) - I$	0	1	1	1	0	0	DH	DI	-		I		٦
ubtrac	SIS	М	ı	Subtract I from M, then skip if borrow	$M \leftarrow (M) - I$ , skip if borrow	0	1	1	1	0	1	DH	DI	-		ı		
0	SIB	М	ı	Subtract I from M with borrow	$M \leftarrow (M) - I - b$	0	1	1	1	1	0	DH	DI	-		I		٦
	SIBS	М	l	Subtract I from M with borrow, then skip if borrow	$M \leftarrow (M) - I - b$ , skip if borrow	0	1	1	1	1	1	DH	DI	-		I		

Continued from preceding page.

Instruc-	Mnemonic	Оре	rand	Function	Operations function						lı	nstructio	on format	
tions	winemonic	1st	2nd	Function	Operations function	f	е	d	С	b	а	9 8	7 6 5 4	3 2 1 0
S	SEQ	r	М	Skip if r equal to M	(r) – (M), skip if zero	0	0	0	1	0	0	DH	DL	r
tion	SEQI	М	1	Skip if M equal to I	(M) – I, skip if zero	0	0	0	1	1	0	DH	DL	I
truc	SNEI	М	1	Skip if M not equal to I	(M) - I, skip if not zero	0	0	0	0	0	1	DH	DL	I
Comparison instructions	SGE	r	М	Skip if r is greater than or equal to M	(r) – (M), skip if not borrow	0	0	0	1	1	0	DH	DL	r
ompari	SGEI	М	ı	Skip if M is greater than equal to I	(M) – I, skip if not borrow	0	0	0	1	1	1	DH	DL	I
O	SLEI	М	ı	Skip if M is less than I	(M) – I, skip if borrow	0	0	0	0	1	1	DH	DL	I
	AND	r	М	AND M with r	$r \leftarrow (r) \text{ AND (M)}$	0	0	1	0	0	0	DH	DL	r
ω	ANDI	М	ı	AND I with M	$M \leftarrow (M) \text{ AND I}$	0	0	1	0	0	1	DH	DL	I
Logic instructions	OR	r	М	OR M with r	$r \leftarrow (r) OR (M)$	0	0	1	0	1	0	DH	DL	r
struc	ORI	М	ı	OR I with M	$M \leftarrow (M) OR I$	0	0	1	0	1	1	DH	DL	I
c in	EXL	r	М	Exclusive OR M with r	$r \leftarrow (r) \text{ XOR (M)}$	0	0	1	1	0	0	DH	DL	r
-ogi	EXLI	М	ı	Exclusive OR M with M	$M \leftarrow (M) XOR I$	0	0	1	1	1	0	DH	DL	I
	SHR	r		Shift r right with carry	carry (r)	0	0	0	0	0	0	0 0	1 1 1 0	r
	LD	r	М	Load M to r	$r \leftarrow (M)$	1	1	0	1	0	0	DH	DL	r
Suc	ST	М	r	Store r to M	$M \leftarrow (r)$	1	1	0	1	0	1	DH	DL	r
structic	MVRD	r	М	Move M to destination M referring to r in the same row	[DH, Rn] ← (M)	1	1	0	1	1	0	DH	DL	r
Transfer instructions	MVRS	М	r	Move source M referring to r to M in the same row	M ← [DH, Rn]	1	1	0	1	1	1	DH	DL	r
Trail	MVSR	M1	M2	Move M to M in the same row	[DH, DL1] ← [DH, DL2]	1	1	1	0	0	0	DH	DL1	DL2
	MVI	М	ı	Move I to M	$M \leftarrow I$	1	1	1	0	0	1	DH	DL	I
tions	TMT	М	N	Test M bits, then skip if all bits specified are true	if M (N) = all 1s, then skip	1	1	1	1	0	0	DH	DL	N
Bit test instructions	TMF	М	N	Test M bits, then skip if all bits specified are false	if M (N) = all 0s, then skip	1	1	1	1	0	1	DH	DL	N
ne	JMP	AD	DR	Jump to the address	PC ← ADDR	1	0	0				Al	DDR (13 bits)	
ubrouti	CAL	AD	DR	Call subroutine	PC ← ADDR Stack ← (PC) + 1	1	0	1				Al	DDR (13 bits)	
nd s	RT			Return from subroutine	PC ← Stack	0	0	0	0	0	0	0 0	1 0 0 0	
Jump and subroutine call instructions	RTI			Return from interrupt	PC ← Stack, BANK ← Stack, CARRY ← Stack	0	0	0	0	0	0	0 0	1 0 0 1	

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		0									1		4 ! .							
Instruc- tions	Mnemonic	Ope	2nd	Function	Operations function	f	е	d	С	b	a	nstru 9	8	7	6		4	3 2	2 1	0
	SS	1st SWR	N	Sat atatus register	(Ctatus M ras) N . 1	1	1	1	1	1	а 1	1	1	0	0	SW			N .	
	RS			Set status register	(Status W-reg) N ← 1	1	1	1	1		1	1		_	1	SW			N N	
Status register instructions		SWR	N	Reset status register	(Status W-reg) N ← 0					1			1	0	انا	_				
le in	TST	SRR	N	Test status register true	if (Status R-reg) N = all	1	1	1	1	1	0	0	0	0		SRR		 	N	
nstr	TSF	SRR	N	Test status register false	if (Status R-reg) N = all	1	1	1	1	1	0	0	0	1	,	SRR		 	N	
Ω	TUL	N		Test Unlock F/F	if Unlock F/F (N) = all 0s, then skip	0	0	0	0	0	0	0	0	1	1	0	1	     	N	
	PLL	ļ N	Л	Load M to PLL register	PLL reg ← PLL data	1	1	1	1	1	0	D	Н		D	L			r	
힏	UCS		I	Set I to UCCW1	UCCW1 ← I	0	0	0	0	0	0	0	0	0	0	0	1		I	
conf	UCC	! !	l	Set I to UCCW2	UCCW2 ← I	0	0	0	0	0	0	0	0	0	0	1	0		ı	
ucti	BEEP		I	Beep control	BEEP reg ← I	0	0	0	0	0	0	0	0	0	1	1	0		1	
Hardware control instructions	DZC		l	Dead zone control	DZC reg ← I	0	0	0	0	0	0	0	0	1	0	1	1		I	
Ha	TMS		l	Set timer register	Timer reg ← I	0	0	0	0	0	0	0	0	1	1	0	0		I	
	IOS	PWn	N	Set port control word	IOS reg PWn ← N	1	1	1	1	1	1	1	0		P۷	Vn			Ν	
	IN	М	Pn	Input port data to M	$M \leftarrow (Pn)$	1	1	1	0	1	0	DI	Н		D	L			Pn	
	OUT	М	Pn	Output contents of M to port	P1n ← M	1	1	1	0	1	1	DI	Н		D	L			Pn	
<u>ء</u>	INR	М	Pn	Input port data to M	$M \leftarrow (Pn)$	0	0	1	1	1	0	DI	Н		D	L			Pn	
gi	SPB	P1n	N	Set port1 bits	(Pn)N ← 1	0	0	0	0	0	0	1	0		Р	n			N	
stru	RPB	P1n	N	Reset port1 bits	(Pn)N ← 0	0	0	0	0	0	0	1	1		Р	n			N	
I/O instructions	TPT	P1n	N	Test port1 bits, then skip if all bits specified are true	if (Pn)N = all 1s, then skip	1	1	1	1	1	1	0	0		Р	n		 	N	
	TPF	P1n	N	Test port1 bits, then skip if all bits specified are false	if (Pn)N = all 0s, then skip	1	1	1	1	1	1	0	1		Р	n			N	
Bank switching instructions	BANK		I	Select Bank	BANK ← I	0	0	0	0	0	0	0	0	0	1	1	1		ı	
	LCDA	М	- 1	Output segment pattern to LCD	LOD (DIOIT)	1	1	0	0	0	0	DI	Н		D	L			IGIT	
l Gigi	LCDB	М	I	digit direct	LCD (DIGIT) ← M	1	1	0	0	0	1	DI	Н		D	L			IGIT	-
LCD	LCPA	М	I	Output segment pattern to LCD	LOD (DIOIT)	1	1	0	0	1	0	DI	Н		D	L			IGIT	-
l ië	LCPB	M I digit through LA			$LCD\ (DIGIT) \leftarrow LA \leftarrow M$	1	1	0	0	1	1	DI	Н		D	L			IGIT	-
Other instructions	HALT		l	Halt mode control	HALT reg ← I, then CPU clock stop	0	0	0	0	0	0	0	0	0	1	0	0		ı	
it of l	CKSTP			Clock stop	Stop x'tal OSC	0	0	0	0	0	0	0	0	0	1	0	1			
ins	NOP			No operation	No operation	0	0	0	0	0	0	0	0	0	0	0	0	<u> </u>		

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